

09/940.774

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,716,760 B2
DATED : April 6, 2004
INVENTOR(S) : Young-Hun Bae et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

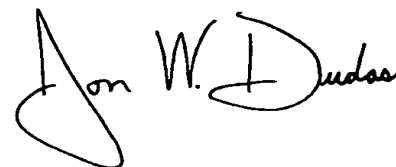
Title page, Item [54] and Column 1, line 5,
Title, please delete "AND" and insert -- AND AN --.

Title page,
Item [75], Inventors, please delete "Icheon" and replace with -- Gyunggi-do --; and delete "Pyungtaek" and replace with -- Gyunggi-do --.

Column 4,
Lines 10-12, please delete "depositing an etching prevention layer wherein the anti-reflection layer and the etching prevention layer are formed of different materials, on the resultant structure;" and replace with -- depositing an etching prevention layer on the resultant structure; --.
Lines 13-14, please delete "depositing an anti-reflection layer on the etching prevention layer;" and replace with -- depositing an anti-reflection layer on the etching prevention layer wherein the anti-reflection layer and the etching prevention layer are formed of different materials, --.
Lines 38-40, please delete "depositing an etching prevention layer wherein the anti-reflection layer and the etching prevention layer are formed of different materials, on the nitride layer," and replace with -- depositing an etching prevention layer on the nitride layer, --.
Lines 41-42, please delete "depositing an anti-reflection layer on the etching prevention layer," and replace with -- depositing an anti-reflection layer on the etching prevention layer wherein the anti-reflection layer and the etching prevention layer are formed of different materials, --.

Signed and Sealed this

Twenty-first Day of December, 2004



JON W. DUDAS
Director of the United States Patent and Trademark Office